# M ixed state Halle ect in the multiphase superconductors

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### A bstract

Halle ect below T  $_{\rm c}$  in multiphase superconductors has been studied on B i-based superconductors. Sam ples with di erent relative content of 2212 and 2223 phase have been prepared. The phase content has been veri ed by X -ray di raction. Results show that while resistance and ac susceptibility is almost insensitive to the content of 2212 phase, the qualitative behavior of the H all resistance is strongly in uenced by the presence of both phases. Theoretical calculation of H all resistance has been made based on e ective medium approximation and compared with experimental results.

Keywords: superconductors, Halle ect PACS: 72.15.Gd, 74.72.-h, 74.25.Fy, 74.60.Ec

#### 1 Introduction

P reparation of single phase high  $T_c$  superconductors is in m any cases di cult technological task, in particular in those with the highest critical tem peratures (B i-, T I- and H g-based m aterials). In such superconductors presence of m inority phase can in uence experimental results and afterwards the interpretation of them as well. Theoretical study of the Halle ect in the m ixed state of high  $T_c$  superconductors did not bring any fully satisfactory explanation of observed experimental results. From the time of classical work of Bardeen et al [1] and N ozieres et al [2] a lot of theoretical work has been published relating the Hall voltage behavior to the ux pinning [3], back ow of therm ally excited quasiparticles [4], layered structure of superconductors [5], a vortex glass transition [6], in balance of the electron density between center and outer region of the vortex [7] or to the interaction am ong norm al state charge carriers, superconducting uid and vortices [8]. A main feature of the Hall voltage is the change of sign with the temperature. One change of sign with decreasing temperature from above  $T_c$  has been observed in YBaCuO superconductors [9], while in Bi- and The based ones two changes of sign have been observed [10]. Recently even tripple change has been observed on Hg samples [11]. With increasing magnetic elds the Hall voltage generally moves to positive values, the change of sign disappears but the number of localm inim a does not change. In this paper we have studied how the mixed state Hall voltage will change if other minority superconducting phase will be present in the sample under study.

This problem has been studied theoretically on the basis of the e ective medium theory and experimentally through resistivity and Halle ect data measured on chosen biphase superconducting materials.

As a material under study B iSrC aC u0 system has been used. The reason for this is that it is rather dicult to prepare a single phase sample and therefore almost always the presence of 2223 and 2212 phases can be present which can in uence the results obtained and therefore also the theoretical interpretation.

# 2 Theory

Only few papers exist describing transport properties of binary mixture i.e. situation where small pieces of a phase 1 are mixed with similar pieces of the second phase 2. Very useful model for such situation is the elective-medium approach originally developed by Bruggem an [12]. This method is designed to deal with the inhom ogeneous media in which dilerent phases are random by distributed in the form of grains of an arbitrary shape, size and orientation. But the form alism is greatly simplied if an assembly of ellipsoids is supposed. Using this model one can calculate elective conductivity for uncorrelated (no correlation between the positions of the grains of dilerent phase) binary mixture [13]. For spherical inclusions one can get

$$_{eff} = \frac{(3x_1 \quad 1)_1 + (3x_2 \quad 1)_2 + ((3x_1 \quad 1)_1 + (3x_2 \quad 1)_2)^2 + 8_{12}}{4}$$
(1)

where  $_1, x_1$  and  $_2, x_2$  are conductivities and fractional volum es of the rst and the second component, respectively. The e ective H allm obility was calculated by W itt in [14] where he obtained

$${}^{H}{}_{eff} = \frac{A_{1} {}^{H}{}_{1}x_{1} {}^{A}{}_{2} {}^{H}{}_{2}x_{2}}{1 {}^{2}(A_{1}x_{1} + A_{2}x_{2})}$$
(2)

with 
$$A_k = (3_{eff} k) = (2_{eff} + k)^2$$
,  $k = 1,2$ .

 $H_1$  and  $H_2$  are Hallm obilities of both subsystem s.

By the application of these form ulas the ohm ic and Hallpart of the e ective resistivity tensor can be derived.

$$= \frac{4}{(X_{1}=1+X_{2}=2+1)^{2}+(X_{1}=1+X_{2}=2)^{2}+8=1}$$
(3)

where  $X_k = 3x_k$  1 for k = 1,2.

$${}^{H} = \frac{1}{1 - 2(Y_1 + Y_2)} \left( \frac{Y_1}{1} + \frac{Y_2}{1} + \frac{Y_2}{2} + \frac{Y_2}{2} \right)$$
(4)

where  $Y_k = 3_k x_k = (2 + k)$  and  $H_k$  for k = 1,2 represent H all resistivities of both phases, respectively. The well known result about percolation threshold for the elective resistivity of superconductor ( $_2 = 0$ ) with admixture of nonsuperconducting particles ( $_1 \in 0$ ) follows from Eq. 3. The resistivity reaches zero value if the superconducting path is established through the sam ple. This situation takes place when 1/3 of total volum e is occupied by superconducting particles (valid for spherical grains) (see F ig. 1). For general ellipsoids another volum e fraction is needed to established superconducting percolation path. The analysis of the form ula for the H all resistivity is not so straightforward. W hile in the case of resistivity only two param eters are present ( $_k$  for k = 1,2), form ula for H includes m oreover H all resistivities for both components. At

rst, we consider case of sample with uniform Hall resistivity but with di erent resistivities of both component to get an image of in uence of these resistivities on e ective Hall resistivity (Fig. 2). We nd that the e ective Hall resistivity of the mixture is lower than values of H all resistivities for both components. The e ective Hall resistivity has minimum for percolation threshold. However, value of this m in imum is positive for arbitrary ratio  $_{2}=_{1}$ . Lowest value approaches 1=4 for 2=1! 0. The sign of the elective Hall resistivity is determ ined by the second term in Eq. 4 because the st term , which depends only on resistivities, can not reach negative values. In Fig. 2 lines of e ective Hall resistivity as a function of volume fraction are drawn for several values of the ratio of  $_2$  to  $_1$  supposing positive  $_{1}^{H} = _{2}^{H}$ . The change of sign is illustrated in the Fig. 3 where the same is made for di erent ratio of  $H_2 = H_1$  at  $_{2}$  = 1! 0. As was mentioned above for the e ective resistivity of mixture of superconducting and nonsuperconducting particles percolation threshold exists at volum e fraction of superconducting phase  $x_2 = 1=3$ . It seems from Fig. 3 that there is no such behavior for e ective H all resistivity with  $_{2}=_{1}!$  0. However it holds for any nonzero ratio  $H_1 = H_2$ . But one should have in m ind that superconductivity with zero resistivity is also supplemented by zero Hall resistivity and so the percolation threshold will be also observed in the Hall resistivity data.

Until now we have studied only concentration dependence of ective resistivi-

ties supposing that resistivities of both components do not change. In the next we would like to use the model of elective mediums to investigate the tem – perature dependence of the elective resistivities. In this case we will assume constant  $x_2$ , which is determined by chemical composition and we will use temperature dependence of pure single component resistivities to determ ine the elective ones. Calculated temperature dependencies of the elective H all resistivity are presented on Fig.4. The calculation is based on the hypothetical temperature dependence (but the qualitative features are in accordance with experiment) of resistivities and H all resistivities describing the behavior of the single 2223 and 2212 phases of B i-based superconductors. Form ixtures of phases curves with double minim a are obtain.

# 3 Experimental results and discussion

For the experimental study B i(P b)SrC aC uO polycrystalline sam ples with varying volume fraction of low  $T_c$  phase (2212) and high  $T_c$  phase (2223) has been prepared together with pure single 2223 phase sam ple by special therm on echanical treatment [15]. The ratio of phases has been controlled by dierent annealing time at 840 ° C and 830 ° C. Shorter time of annealing means lower content of 2223 phase. Relative volumes of superconducting phases have been determined by X-ray dieraction studies. In addition to the resistivity and H all e ect the ac and dc susceptibility has been also determined.

Resistances and Hallresistances in magnetic eld 4 T for the samples with 2223 phase volume fraction 100%, 75%, 50% are shown in Fig. 5.0 ne can see that while single phase samples reveal only one local minim a in the tem perature dependence of the Hall resistance, samples in which both phases are present show two localm inim a before going to zero at low tem peratures. Com parison with Fig. 5 reveals qualitative agreement with calculated curves based on the e ective medium model. However one can see that the experimental curves quantitatively disagree with presented theoretical model. The reason for this is probably connected with the roughness of the model used. The roughness of the mentioned model follows at least from the assumption of spherical shape of grains, which is certainly not the case of high T<sub>c</sub> superconductors. In our calculation we also suppose that di erent phases are not correlated which can not be ful lled as well. Moreover it is well known [16] that the volume fractions of di erent phases determ ined from the resistivity and susceptibility measured at very low magnetic elds do not agree with those determined by X-ray di raction.W hile the two above mentioned measurements can not "see" lower phase if its grains are covered by a thin layer of 2223 phase, the X -ray can.

#### 4 Conclusion

The form ulas for the e ective H all resistivity have been derived on the basis of the e ective medium approach. The calculated temperature dependence has been compared with the experimentally obtained curves and qualitative agreement has been obtained. The results con med that in the multiphase samples several localminim a can be observed in the temperature dependence of the H all resistivities due to the presence of two phases with dierent H all resistivities. This means, that not only the mechanism us described by K opnin [17] can be responsible for observed results in [11]. From this work follows that one must be careful in the interpretation of the qualitative features of experimentally determined H all e ect. However, one must have in mind that the used m odel is too simple to get quantitative agreement.

# 5 A cknow ledgem ents

This work has been supported by GACR under project No. 202/00/1602 and by GAAS under project No. A 1010919/99 and by M inistry of Education under research plan No. 173100003

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# Figure captions

Fig. 1: Normalized e ective resistivity  $=_1$  as a function of volume fraction  $x_2$  for di erent ratio of single phase resistivities  $_2=_1$ .

Fig. 2: Normalized e ective Hall resistivity  ${}^{H} = {}_{1}{}^{H}$  as a function of volume fraction  $x_2$  for di erent ratio of single phase resistivities  ${}_{2}={}_{1}$  and equal Hall resistivities ( ${}_{2}{}^{H}={}_{1}{}^{H}={}_{1}$ ).

Fig. 3: Normalized e ective Hall resistivity  ${}^{H} = {}_{1}{}^{H}$  as a function of volume fraction  $x_{2}$  for parameter  ${}_{2}={}_{1}$ ! 0 and parameter  ${}_{2}{}^{H} = {}_{1}{}^{H}$  equal + 1,0,-1, respectively. For comparison the dot curve for  $={}_{1}$  is shown.

Fig. 4: Calculated temperature dependencies of e ective resistivity (a) and e ective Hall resistivity (b) for di erent volum e fraction based on assumed temperature dependence of single phase samples (0%,100 %). The presented curves correspond to low magnetic eld where sign changes of the Hall resistivity are usually observed.

Fig. 5: Tem perature dependencies of norm alized resistivity (a) and H all resistivity (b) for samples with di erent volum e fraction of 2223 phase m easured at 4T (in (a): -100 %, 2 -75%, A -50 %).

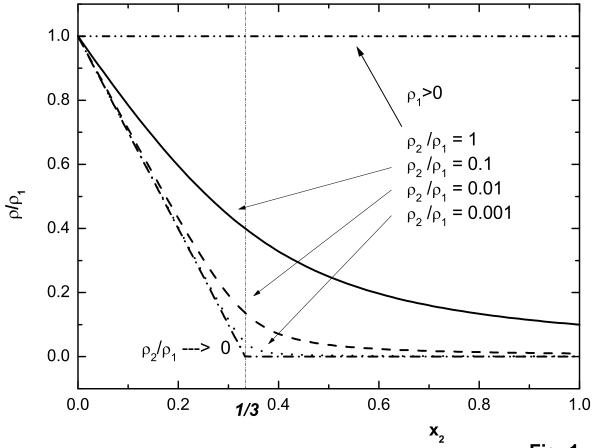


Fig. 1

